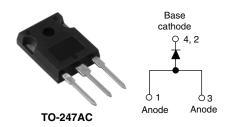




Vishay High Power Products

### Input Rectifier Diode, 80 A



| PRODUCT SUMMARY        |        |  |  |
|------------------------|--------|--|--|
| V <sub>F</sub> at 80 A | 1.17 V |  |  |
| I <sub>FSM</sub>       | 1450 A |  |  |
| V <sub>RRM</sub>       | 1600 V |  |  |

#### **DESCRIPTION/FEATURES**

The 80EPS16 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

| MAJOR RATINGS AND CHARACTERISTICS |                              |             |       |  |  |
|-----------------------------------|------------------------------|-------------|-------|--|--|
| SYMBOL                            | CHARACTERISTICS              | VALUES      | UNITS |  |  |
| I <sub>F(AV)</sub>                | Sinusoidal waveform          | 80          | А     |  |  |
| $V_{RRM}$                         |                              | 1600        | V     |  |  |
| I <sub>FSM</sub>                  |                              | 1450        | Α     |  |  |
| V <sub>F</sub>                    | 80 A, T <sub>J</sub> = 25 °C | 1.17        | V     |  |  |
| T <sub>J</sub>                    |                              | - 40 to 150 | °C    |  |  |

| VOLTAGE RATINGS |   |  |                                     |  |  |
|-----------------|---|--|-------------------------------------|--|--|
| PART NUMBER     | V <sub>RRM</sub> , MAXIMUM<br>PEAK REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub><br>AT 150 °C<br>mA |  |  |
| 80EPS16         | 1600  | 1700   | 1                                   |  |  |

| ABSOLUTE MAXIMUM RATINGS                            |  |   |        |                  |  |
|---|--|---|--------|------------------|--|
| PARAMETER   | SYMBOL   | TEST CONDITIONS                                   | VALUES | UNITS            |  |
| Maximum average forward current                     | I <sub>F(AV)</sub>                               | $T_C = 100$ °C, $180$ ° conduction half sine wave | 80     |                  |  |
| Maximum peak one cycle non-repetitive surge current | 10 ms sine pulse, rated V <sub>RRM</sub> applied | 1450  | Α      |                  |  |
|   | IFSM   | 10 ms sine pulse, no voltage reapplied            | 1500   | 1                |  |
| Maximum I <sup>2</sup> t for fusing                 | l <sup>2</sup> t                                 | 10 ms sine pulse, rated V <sub>RRM</sub> applied  | 10 500 | A <sup>2</sup> s |  |
|   |  | 10 ms sine pulse, no voltage reapplied            | 14 000 |                  |  |
| Maximum I <sup>2</sup> √t for fusing                | I²√t   | t = 0.1 ms to 10 ms, no voltage reapplied 105 000 |        | A²√s             |  |

# 80EPS16 High Voltage Series

## Vishay High Power Products Input Rectifier Diode, 80 A



| ELECTRICAL SPECIFICATIONS       |                    |                              |   |        |       |
|---------------------------------|--------------------|------------------------------|---|--------|-------|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS              |   | VALUES | UNITS |
| Maximum forward voltage drop    | V <sub>FM</sub>    | 80 A, T <sub>J</sub> = 25 °C |   | 1.17   | V     |
| Forward slope resistance        | r <sub>t</sub>     | - T <sub>J</sub> = 150 °C    |   | 3.17   | mΩ    |
| Threshold voltage               | V <sub>F(TO)</sub> |                              |   | 0.73   | V     |
| Maximum reverse leakage current | 1                  | T <sub>J</sub> = 25 °C       | V <sub>R</sub> = Rated V <sub>RRM</sub> | 0.1    | mA    |
|                                 | IRM                | T <sub>J</sub> = 150 °C      | VH - Haleu VHHM                         | 1.0    | 111/4 |

| THERMAL - MECHAN                                | THERMAL - MECHANICAL SPECIFICATIONS |                                   |                                      |                          |            |
|---|-------------------------------------|-----------------------------------|--------------------------------------|--------------------------|------------|
| PARAMETER                                       |                                     | SYMBOL TEST CONDITIONS            |                                      | VALUES                   | UNITS      |
| Maximum junction and storage temperature range  |                                     | T <sub>J</sub> , T <sub>Stg</sub> |                                      | - 40 to 150              | °C         |
| Maximum thermal resistance, junction to case    |                                     | $R_{\text{thJC}}$                 | DC operation                         | 0.35                     |            |
| Maximum thermal resistance, junction to ambient |                                     | R <sub>thJA</sub>                 |                                      | 40                       | °C/W       |
| Typical thermal resistance, case to heatsink    |                                     | R <sub>thCS</sub>                 | Mounting surface, smooth and greased | 0.2                      |            |
| Approximate weight                              |                                     |                                   | 6                                    | g                        |            |
|   |                                     |                                   | 0.21                                 | oz.                      |            |
| Mounting torque —                               | minimum                             |                                   |                                      | 6 (5)                    | kgf ⋅ cm   |
|   | maximum                             |                                   |                                      | 12 (10)                  | (lbf · in) |
| Marking device                                  |                                     |                                   | Case style TO-247AC (JEDEC)          | TO-247AC (JEDEC) 80EPS16 |            |



### Input Rectifier Diode, 80 A Vishay High Power Products

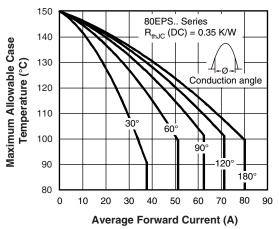
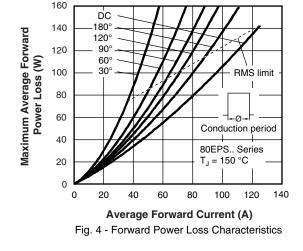


Fig. 1 - Current Rating Characteristics



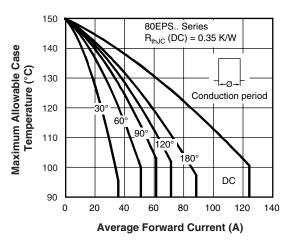


Fig. 2 - Current Rating Characteristics

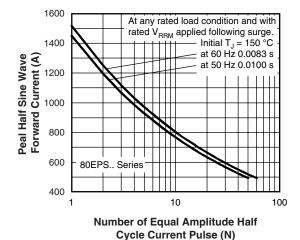


Fig. 5 - Maximum Non-Repetitive Surge Current

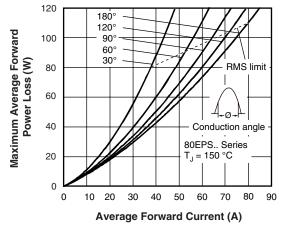


Fig. 3 - Forward Power Loss Characteristics

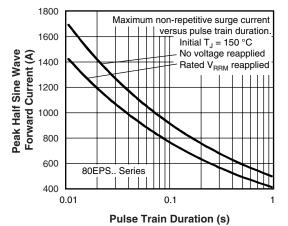


Fig. 6 - Maximum Non-Repetitive Surge Current

## Vishay High Power Products Input Rectifier Diode, 80 A



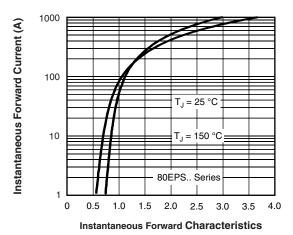


Fig. 7 - Forward Voltage Drop Characteristics

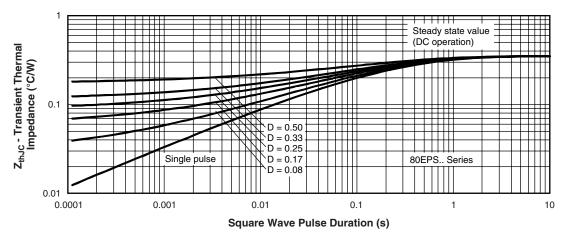


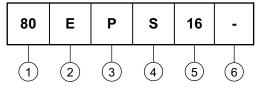
Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

## 80EPS16 High Voltage Series

Input Rectifier Diode, 80 A Vishay High Power Products

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Current rating (80 = 80 A)

2 - Circuit configuration:

E = Single diode

Package:

P = TO-247AC

4 - Type of silicon:

S = Standard recovery rectifier

5 - Voltage rating (16 = 1600 V)

6 - • None = Standard production

• PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS                 |                          |  |  |
|--|--------------------------|--|--|
| Dimensions <u>www.vishay.com/doc?95223</u> |                          |  |  |
| Part marking information                   | www.vishay.com/doc?95226 |  |  |



Vishay

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